

## Description

The GM71C4100B/BL is the new generation dynamic RAM organized 4,194,304 x 1 bit. GM71C4100B/BL has realized higher density, higher performance and various functions by utilizing advanced CMOS process technology. The GM71C4100B/BL offers Fast Page Mode as a high speed access Mode. Multiplexed address inputs permit the GM71C4100B/BL to be packaged in a standard 300mil 20pin plastic SOJ, standard 400mil 20pin plastic ZIP, and standard 300mil 20pin plastic TSOP II. The package size provides high system bit densities and is compatible with widely available automated testing and insertion equipment. System oriented features include single power supply of  $5V \pm 10\%$  tolerance, direct interfacing capability with high performance logic families such as Schottky TTL.

## Features

- 4,194,304 Words x 1 Bit Organization
- Fast Page Mode Capability
- Single Power Supply ( $5V \pm 10\%$ )
- Fast Access Time & Cycle Time

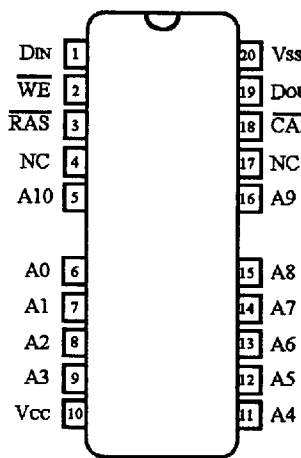
(Unit: ns)

|                  | t <sub>rac</sub> | t <sub>cac</sub> | t <sub>rc</sub> | t <sub>pc</sub> |
|------------------|------------------|------------------|-----------------|-----------------|
| GM71C4100B/BL-60 | 60               | 15               | 110             | 40              |
| GM71C4100B/BL-70 | 70               | 20               | 130             | 45              |
| GM71C4100B/BL-80 | 80               | 20               | 150             | 50              |

- Low Power  
Active : 605/550/495mW (MAX)  
Standby : 5.5mW (CMOS level : MAX)  
1.1mW (L-series)
- $\overline{\text{RAS}}$  Only Refresh,  $\overline{\text{CAS}}$  before  $\overline{\text{RAS}}$  Refresh, Hidden Refresh Capability
- All inputs and outputs TTL Compatible
- 1024 Refresh Cycles/16ms
- 1024 Refresh Cycles/128ms (L-series)
- Battery Back Up Operation (L-series)

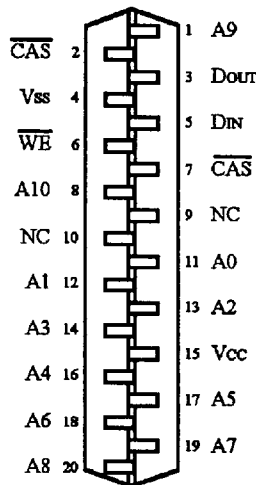
## Pin Configuration

**20 (26) SOJ**



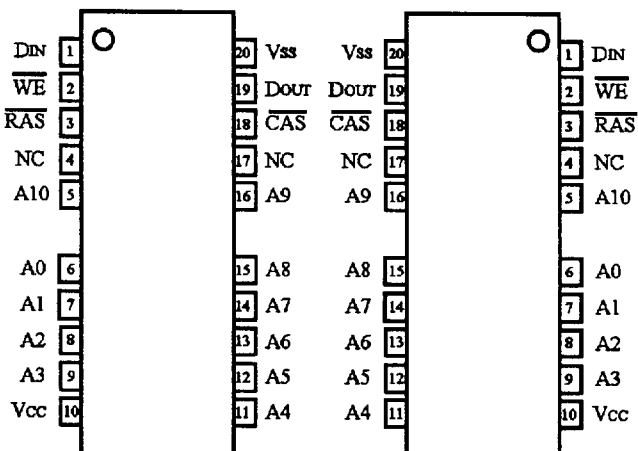
**(Top View)**

**20 ZIP**



**(Bottom View)**

**20 (26) TSOP II**



**GM71C4100BT/BLT**

**GM71C4100BR/BLR**

**(Top View)**



### Pin Description

| Pin                     | Function               | Pin                     | Function              |
|-------------------------|------------------------|-------------------------|-----------------------|
| A0-A10                  | Address Inputs         | $\overline{\text{CAS}}$ | Column Address Strobe |
| A0-A9                   | Refresh Address Inputs | $\overline{\text{WE}}$  | Read/Write Enable     |
| $\text{D}_{\text{IN}}$  | Data Input             | $\text{V}_{\text{CC}}$  | Power (+5V)           |
| $\text{D}_{\text{OUT}}$ | Data Output            | $\text{V}_{\text{SS}}$  | Ground                |
| $\overline{\text{RAS}}$ | Row Address Strobe     | NC                      | No Connection         |

### Ordering Information

| Type No.                                                       | Access Time             | Package                                                   |
|----------------------------------------------------------------|-------------------------|-----------------------------------------------------------|
| GM71C4100BJ/BLJ-60<br>GM71C4100BJ/BLJ-70<br>GM71C4100BJ/BLJ-80 | 60 ns<br>70 ns<br>80 ns | 300 Mil, 20 (26) Pin<br>Plastic SOJ                       |
| GM71C4100BZ/BLZ-60<br>GM71C4100BZ/BLZ-70<br>GM71C4100BZ/BLZ-80 | 60 ns<br>70 ns<br>80 ns | 400 Mil, 20 Pin<br>Plastic ZIP                            |
| GM71C4100BT/BLT-60<br>GM71C4100BT/BLT-70<br>GM71C4100BT/BLT-80 | 60 ns<br>70 ns<br>80 ns | 300 Mil, 20 (26) Pin<br>Plastic TSOP II<br>(Normal Type)  |
| GM71C4100BR/BLR-60<br>GM71C4100BR/BLR-70<br>GM71C4100BR/BLR-80 | 60 ns<br>70 ns<br>80 ns | 300 Mil, 20 (26) Pin<br>Plastic TSOP II<br>(Reverse Type) |

### Absolute Maximum Ratings\*

| Symbol                                       | Parameter                                                            | Rating     | Unit |
|----------------------------------------------|----------------------------------------------------------------------|------------|------|
| $T_{\text{A}}$                               | Ambient Temperature under Bias                                       | 0 ~ 70     | °C   |
| $T_{\text{STG}}$                             | Storage Temperature (Plastic)                                        | -55 ~ 125  | °C   |
| $\text{V}_{\text{IN}}/\text{V}_{\text{OUT}}$ | Voltage on any Pin Relative to $\text{V}_{\text{SS}}$                | -1.0 ~ 7.0 | V    |
| $\text{V}_{\text{CC}}$                       | Voltage on $\text{V}_{\text{CC}}$ Relative to $\text{V}_{\text{SS}}$ | -1.0 ~ 7.0 | V    |
| $\text{I}_{\text{OUT}}$                      | Short Circuit Output Current                                         | 50         | mA   |
| $\text{P}_{\text{D}}$                        | Power Dissipation                                                    | 1.0        | W    |

\*Note: Operation at or above Absolute Maximum Ratings can adversely affect device reliability.

### Recommended DC Operating Conditions ( $T_{\text{A}} = 0 \sim 70^{\circ}\text{C}$ )

| Symbol                 | Parameter          | Min  | Typ | Max | Unit |
|------------------------|--------------------|------|-----|-----|------|
| $\text{V}_{\text{CC}}$ | Supply Voltage     | 4.5  | 5.0 | 5.5 | V    |
| $\text{V}_{\text{IH}}$ | Input High Voltage | 2.4  | -   | 6.5 | V    |
| $\text{V}_{\text{IL}}$ | Input Low Voltage  | -1.0 | -   | 0.8 | V    |

**DC Electrical Characteristics** ( $V_{CC} = 5V \pm 10\%$ ,  $T_A = 0 \sim 70^\circ C$ )

| Symbol    | Parameter                                                                                                                                                                                                                  | Min  | Max      | Unit    | Note       |
|-----------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|----------|---------|------------|
| $V_{OH}$  | Output Level<br>Output "H" Level Voltage ( $I_{OUT} = -5mA$ )                                                                                                                                                              | 2.4  | $V_{CC}$ | V       |            |
| $V_{OL}$  | Output Level<br>Output "L" Level Voltage ( $I_{OUT} = 4.2mA$ )                                                                                                                                                             | 0    | 0.4      | V       |            |
| $I_{CC1}$ | Operating Current<br>Average Power Supply Operating Current<br>( $\overline{RAS}$ , $\overline{CAS}$ Cycling: $t_{RC} = t_{RC \min}$ )                                                                                     | 60ns | -        | 110     | mA<br>1, 2 |
|           |                                                                                                                                                                                                                            | 70ns | -        | 100     |            |
|           |                                                                                                                                                                                                                            | 80ns | -        | 90      |            |
| $I_{CC2}$ | Standby Current (TTL)<br>Power Supply Standby Current<br>( $\overline{RAS}$ , $\overline{CAS} = V_{IH}$ , $DOUT = High-Z$ )                                                                                                | -    | 2        | mA      |            |
| $I_{CC3}$ | $\overline{RAS}$ -Only Refresh Current<br>Average Power Supply Current<br>$\overline{RAS}$ -Only Refresh Mode<br>( $\overline{RAS}$ Cycling, $\overline{CAS} = V_{IH}$ , $t_{RC} = t_{RC \min}$ )                          | 60ns | -        | 110     | mA<br>2    |
|           |                                                                                                                                                                                                                            | 70ns | -        | 100     |            |
|           |                                                                                                                                                                                                                            | 80ns | -        | 90      |            |
| $I_{CC4}$ | Fast Page Mode Current<br>Average Power Supply Current<br>Fast Page Mode<br>( $\overline{RAS} = V_{IL}$ , $\overline{CAS}$ , Address Cycling: $t_{RC} = t_{RC \min}$ )                                                     | 60ns | -        | 110     | mA<br>1, 3 |
|           |                                                                                                                                                                                                                            | 70ns | -        | 100     |            |
|           |                                                                                                                                                                                                                            | 80ns | -        | 90      |            |
| $I_{CC5}$ | Standby Current (CMOS)<br>Power Supply Standby Current<br>( $\overline{RAS}$ , $\overline{CAS} = V_{IH}$ , $\overline{WE}$ , Address, $DIN = V_{IH}$ or $V_{IL}$ , $DOUT = High-Z$ )                                       | -    | 1        | mA      | 5          |
|           |                                                                                                                                                                                                                            | -    | 200      | $\mu A$ | 4, 5       |
| $I_{CC6}$ | $\overline{CAS}$ -before- $\overline{RAS}$ Refresh Current<br>( $t_{RC} = t_{RC \min}$ )                                                                                                                                   | 60ns | -        | 110     | mA         |
|           |                                                                                                                                                                                                                            | 70ns | -        | 100     |            |
|           |                                                                                                                                                                                                                            | 80ns | -        | 90      |            |
| $I_{CC7}$ | Battery Back Up Current<br>(Standby with CBR Refresh)<br>( $t_{RC} = 125\mu s$ , $t_{RAS} \leq 1\mu s$ , $\overline{WE} = V_{IH}$ , $\overline{CAS} = V_{IL}$ , Address and $DIN = V_{IH}$ or $V_{IL}$ , $DOUT = High-Z$ ) | -    | 300      | $\mu A$ | 4, 5       |
| $I_{CC8}$ | Standby Current $\overline{RAS} = V_{IH}$<br>$\overline{CAS} = V_{IL}$<br>$DOUT = Enable$                                                                                                                                  | -    | 5        | mA      | 1          |
| $I_{IL}$  | Input Leakage Current<br>Any Input ( $0V \leq V_{IN} \leq 7V$ )                                                                                                                                                            | -10  | 10       | $\mu A$ |            |
| $I_{OL}$  | Output Leakage Current<br>( $DOUT$ is Disabled, $0V \leq V_{OUT} \leq 7V$ )                                                                                                                                                | -10  | 10       | $\mu A$ |            |

Note: 1.  $I_{CC}$  depends on output load condition when the device is selected.  $I_{CC}(\max)$  is specified at the output open condition.

2. Address can be changed once or less while  $\overline{RAS} = V_{IL}$ .

3. Address can be changed once or less while  $\overline{CAS} = V_{IH}$ .

4. L Series.

5.  $V_{CC} - 0.2V \leq V_{IH} \leq 6.5V$ ,  $0V \leq V_{IL} \leq 0.2V$ .

**Capacitance** ( $V_{CC} = 5V \pm 10\%$ ,  $T_A = 25^\circ C$ )

| Symbol   | Parameter                              | Min | Max | Unit | Note |
|----------|----------------------------------------|-----|-----|------|------|
| $C_{II}$ | Input Capacitance (Address, $D_{IN}$ ) | -   | 5   | pF   | 1    |
| $C_{I2}$ | Input Capacitance (Clocks)             | -   | 7   | pF   | 1    |
| $C_O$    | Output Capacitance ( $D_{OUT}$ )       | -   | 7   | pF   | 1, 2 |

Note: 1. Capacitance measured with Boonton Meter or effective capacitance measuring method.  
 2.  $\overline{CAS} = V_{IH}$  to disable  $D_{OUT}$ .

**AC Characteristics** ( $V_{CC} = 5V \pm 10\%$ ,  $T_A = 0 \sim 70^\circ C$ , Notes 1, 2, 15)

Test Conditions

Input rise and fall times: 5ns

Output load : 2 TTL gate +  $C_L$  (100pF)

Input, output timing reference levels: 0.8V, 2.4V

(Including scope and jig)

**Read, Write, Read-Modify-Write and Refresh Cycles (Common Parameters)**

| Symbol    | Parameter                                           | GM71C4100<br>B/BL-60 |        | GM71C4100<br>B/BL-70 |        | GM71C4100<br>B/BL-80 |        | Unit | Note     |
|-----------|-----------------------------------------------------|----------------------|--------|----------------------|--------|----------------------|--------|------|----------|
|           |                                                     | Min                  | Max    | Min                  | Max    | Min                  | Max    |      |          |
| $t_{RC}$  | Random Read or Write Cycle Time                     | 110                  | -      | 130                  | -      | 150                  | -      | ns   |          |
| $t_{RP}$  | $\overline{RAS}$ Precharge Time                     | 40                   | -      | 50                   | -      | 60                   | -      | ns   |          |
| $t_{RAS}$ | $\overline{RAS}$ Pulse Width                        | 60                   | 10,000 | 70                   | 10,000 | 80                   | 10,000 | ns   |          |
| $t_{CAS}$ | $\overline{CAS}$ Pulse Width                        | 15                   | 10,000 | 20                   | 10,000 | 20                   | 10,000 | ns   |          |
| $t_{ASR}$ | Row Address Set-up Time                             | 0                    | -      | 0                    | -      | 0                    | -      | ns   |          |
| $t_{RAH}$ | Row Address Hold Time                               | 10                   | -      | 10                   | -      | 10                   | -      | ns   |          |
| $t_{ASC}$ | Column Address Set-up Time                          | 0                    | -      | 0                    | -      | 0                    | -      | ns   |          |
| $t_{CAH}$ | Column Address Hold Time                            | 15                   | -      | 15                   | -      | 15                   | -      | ns   |          |
| $t_{RCD}$ | $\overline{RAS}$ to $\overline{CAS}$ Delay Time     | 20                   | 45     | 20                   | 50     | 20                   | 60     | ns   | 8        |
| $t_{RAD}$ | $\overline{RAS}$ to Column Address Delay Time       | 15                   | 30     | 15                   | 35     | 15                   | 40     | ns   | 9        |
| $t_{RSH}$ | $\overline{RAS}$ Hold Time                          | 15                   | -      | 20                   | -      | 20                   | -      | ns   |          |
| $t_{CSH}$ | $\overline{CAS}$ Hold Time                          | 60                   | -      | 70                   | -      | 80                   | -      | ns   |          |
| $t_{CRP}$ | $\overline{CAS}$ to $\overline{RAS}$ Precharge Time | 10                   | -      | 10                   | -      | 10                   | -      | ns   |          |
| $t_T$     | Transition Time<br>(Rise and Fall)                  | 3                    | 50     | 3                    | 50     | 3                    | 50     | ns   | 7        |
| $t_{REF}$ | Refresh Period (1024 Cycles)                        | -                    | 16     | -                    | 16     | -                    | 16     | ms   |          |
|           | Refresh Period (1024 Cycles)                        | -                    | 128    | -                    | 128    | -                    | 128    | ms   | L-Series |

### Read Cycle

| Symbol           | Parameter                                           | GM71C4100<br>B/BL-60 |     | GM71C4100<br>B/BL-70 |     | GM71C4100<br>B/BL-80 |     | Unit | Note            |
|------------------|-----------------------------------------------------|----------------------|-----|----------------------|-----|----------------------|-----|------|-----------------|
|                  |                                                     | Min                  | Max | Min                  | Max | Min                  | Max |      |                 |
| t <sub>RAC</sub> | Access Time from $\overline{\text{RAS}}$            | -                    | 60  | -                    | 70  | -                    | 80  | ns   | 2,3,16          |
| t <sub>CAC</sub> | Access Time from $\overline{\text{CAS}}$            | -                    | 15  | -                    | 20  | -                    | 20  | ns   | 3, 4,<br>14, 16 |
| t <sub>AA</sub>  | Access Time from Address                            | -                    | 30  | -                    | 35  | -                    | 40  | ns   | 3, 5,<br>14, 16 |
| t <sub>RCS</sub> | Read Command Setup Time                             | 0                    | -   | 0                    | -   | 0                    | -   | ns   |                 |
| t <sub>RCH</sub> | Read Command Hold Time to $\overline{\text{CAS}}$   | 0                    | -   | 0                    | -   | 0                    | -   | ns   |                 |
| t <sub>RRH</sub> | Read Command Hold Time to $\overline{\text{RAS}}$   | 0                    | -   | 0                    | -   | 0                    | -   | ns   |                 |
| t <sub>RAL</sub> | Column Address to $\overline{\text{RAS}}$ Lead Time | 30                   | -   | 35                   | -   | 40                   | -   | ns   |                 |
| t <sub>OFF</sub> | Output Buffer Turn-off Time                         | 0                    | 15  | 0                    | 20  | 0                    | 20  | ns   | 6               |

### Write Cycle

| Symbol           | Parameter                                          | GM71C4100<br>B/BL-60 |     | GM71C4100<br>B/BL-70 |     | GM71C4100<br>B/BL-80 |     | Unit | Note |
|------------------|----------------------------------------------------|----------------------|-----|----------------------|-----|----------------------|-----|------|------|
|                  |                                                    | Min                  | Max | Min                  | Max | Min                  | Max |      |      |
| t <sub>WCS</sub> | Write Command Setup Time                           | 0                    | -   | 0                    | -   | 0                    | -   | ns   | 10   |
| t <sub>WCH</sub> | Write Command Hold Time                            | 15                   | -   | 15                   | -   | 15                   | -   | ns   |      |
| t <sub>WP</sub>  | Write Command Pulse Width                          | 10                   | -   | 10                   | -   | 10                   | -   | ns   |      |
| t <sub>RWL</sub> | Write Command to $\overline{\text{RAS}}$ Lead Time | 15                   | -   | 20                   | -   | 20                   | -   | ns   |      |
| t <sub>CWL</sub> | Write Command to $\overline{\text{CAS}}$ Lead Time | 15                   | -   | 20                   | -   | 20                   | -   | ns   |      |
| t <sub>DS</sub>  | Data-in Setup Time                                 | 0                    | -   | 0                    | -   | 0                    | -   | ns   | 11   |
| t <sub>DH</sub>  | Data-in Hold Time                                  | 15                   | -   | 15                   | -   | 15                   | -   | ns   | 11   |

### Read-Modify-Write Cycle

| Symbol           | Parameter                                                    | GM71C4100<br>B/BL-60 |     | GM71C4100<br>B/BL-70 |     | GM71C4100<br>B/BL-80 |     | Unit | Note |
|------------------|--------------------------------------------------------------|----------------------|-----|----------------------|-----|----------------------|-----|------|------|
|                  |                                                              | Min                  | Max | Min                  | Max | Min                  | Max |      |      |
| t <sub>RWC</sub> | Read-Modify-Write Cycle Time                                 | 130                  | -   | 155                  | -   | 175                  | -   | ns   |      |
| t <sub>RWD</sub> | $\overline{\text{RAS}}$ to $\overline{\text{WE}}$ Delay Time | 60                   | -   | 70                   | -   | 80                   | -   | ns   | 10   |
| t <sub>CWD</sub> | $\overline{\text{CAS}}$ to $\overline{\text{WE}}$ Delay Time | 15                   | -   | 20                   | -   | 20                   | -   | ns   | 10   |
| t <sub>AWD</sub> | Column Address to $\overline{\text{WE}}$ Delay Time          | 30                   | -   | 35                   | -   | 40                   | -   | ns   | 10   |

### Refresh Cycle

| Symbol           | Parameter                                                                                                        | GM71C4100<br>B/BL-60 |     | GM71C4100<br>B/BL-70 |     | GM71C4100<br>B/BL-80 |     | Unit | Note |
|------------------|------------------------------------------------------------------------------------------------------------------|----------------------|-----|----------------------|-----|----------------------|-----|------|------|
|                  |                                                                                                                  | Min                  | Max | Min                  | Max | Min                  | Max |      |      |
| t <sub>CSR</sub> | $\overline{\text{CAS}}$ Set-up Time<br>( $\overline{\text{CAS}}$ -before- $\overline{\text{RAS}}$ Refresh Cycle) | 10                   | -   | 10                   | -   | 10                   | -   | ns   |      |
| t <sub>CHR</sub> | $\overline{\text{CAS}}$ Hold Time<br>( $\overline{\text{CAS}}$ -before- $\overline{\text{RAS}}$ Refresh Cycle)   | 10                   | -   | 10                   | -   | 10                   | -   | ns   |      |
| t <sub>RPC</sub> | $\overline{\text{RAS}}$ Precharge to $\overline{\text{CAS}}$ Hold Time                                           | 10                   | -   | 10                   | -   | 10                   | -   | ns   |      |
| t <sub>CPN</sub> | $\overline{\text{CAS}}$ Precharge Time in Normal Mode                                                            | 10                   | -   | 10                   | -   | 10                   | -   | ns   |      |

### Fast Page Mode Cycle

| Symbol            | Parameter                                                                | GM71C4100<br>B/BL-60 |         | GM71C4100<br>B/BL-70 |         | GM71C4100<br>B/BL-80 |         | Unit | Note    |
|-------------------|--------------------------------------------------------------------------|----------------------|---------|----------------------|---------|----------------------|---------|------|---------|
|                   |                                                                          | Min                  | Max     | Min                  | Max     | Min                  | Max     |      |         |
| t <sub>PC</sub>   | Fast Page Mode Cycle Time                                                | 40                   | -       | 45                   | -       | 50                   | -       | ns   |         |
| t <sub>CP</sub>   | Fast Page Mode $\overline{\text{CAS}}$ Precharge Time                    | 10                   | -       | 10                   | -       | 10                   | -       | ns   |         |
| t <sub>RASC</sub> | Fast Page Mode $\overline{\text{RAS}}$ Pulse Width                       | -                    | 100,000 | -                    | 100,000 | -                    | 100,000 | ns   | 14      |
| t <sub>ACP</sub>  | Access Time from $\overline{\text{CAS}}$ Precharge                       | -                    | 35      | -                    | 40      | -                    | 45      | ns   | 3,14,16 |
| t <sub>RHCP</sub> | $\overline{\text{RAS}}$ Hold Time from $\overline{\text{CAS}}$ Precharge | 35                   | -       | 40                   | -       | 45                   | -       | ns   |         |

### Fast Page Mode Read-Modify-Write Cycle

| Symbol           | Parameter                                                              | GM71C4100<br>B/BL-60 |     | GM71C4100<br>B/BL-70 |     | GM71C4100<br>B/BL-80 |     | Unit | Note |
|------------------|------------------------------------------------------------------------|----------------------|-----|----------------------|-----|----------------------|-----|------|------|
|                  |                                                                        | Min                  | Max | Min                  | Max | Min                  | Max |      |      |
| t <sub>PCM</sub> | Fast Page Mode Read-Modify-Write Cycle Time                            | 60                   | -   | 70                   | -   | 75                   | -   | ns   |      |
| t <sub>CPW</sub> | $\overline{\text{CAS}}$ Precharge to $\overline{\text{WE}}$ Delay Time | 35                   | -   | 40                   | -   | 45                   | -   | ns   |      |

### Test Mode Cycle

| Symbol          | Parameter                                   | GM71C4100<br>B/BL-60 |     | GM71C4100<br>B/BL-70 |     | GM71C4100<br>B/BL-80 |     | Unit | Note |
|-----------------|---------------------------------------------|----------------------|-----|----------------------|-----|----------------------|-----|------|------|
|                 |                                             | Min                  | Max | Min                  | Max | Min                  | Max |      |      |
| t <sub>WS</sub> | Test Mode $\overline{\text{WE}}$ Setup Time | 0                    | -   | 0                    | -   | 0                    | -   | ns   |      |
| t <sub>WH</sub> | Test Mode $\overline{\text{WE}}$ Hold Time  | 10                   | -   | 10                   | -   | 10                   | -   | ns   |      |

## Counter Test Cycle

| Symbol           | Parameter                                                    | GM71C4100<br>B/BL-60 |     | GM71C4100<br>B/BL-70 |     | GM71C4100<br>B/BL-80 |     | Unit | Note |
|------------------|--------------------------------------------------------------|----------------------|-----|----------------------|-----|----------------------|-----|------|------|
|                  |                                                              | Min                  | Max | Min                  | Max | Min                  | Max |      |      |
| t <sub>CPT</sub> | $\overline{\text{CAS}}$ Precharge Time in Counter Test Cycle | 40                   | -   | 40                   | -   | 40                   | -   | ns   |      |

### Notes:

1. AC Measurements assume  $t_r = 5\text{ ns}$ .
2. Assumes that  $t_{\text{rCD}} \leq t_{\text{rCD}}(\text{max})$  and  $t_{\text{rAD}} \leq t_{\text{rAD}}(\text{max})$ . If  $t_{\text{rCD}}$  or  $t_{\text{rAD}}$  is greater than the maximum recommended value shown in this table,  $t_{\text{rAC}}$  exceeds the value shown.
3. Measured with a load circuit equivalent to 2TTL loads and 100pF.
4. Assumes that  $t_{\text{rCD}} \geq t_{\text{rCD}}(\text{max})$  and  $t_{\text{rAD}} \leq t_{\text{rAD}}(\text{max})$ .
5. Assumes that  $t_{\text{rCD}} \leq t_{\text{rCD}}(\text{max})$  and  $t_{\text{rAD}} \geq t_{\text{rAD}}(\text{max})$ .
6.  $t_{\text{off}}(\text{max})$  defines the time at which the output achieves the open circuit condition and is not referenced to output voltage levels.
7.  $V_{\text{IH}}(\text{max})$  and  $V_{\text{IL}}(\text{max})$  are reference levels for measuring timing of input signals. Also, transition times are measured between  $V_{\text{IH}}$  and  $V_{\text{IL}}$ .
8. Operation with the  $t_{\text{rAD}}(\text{max})$  limit insures that  $t_{\text{rAC}}(\text{max})$  can be met,  $t_{\text{rCD}}(\text{max})$  is specified as a reference point only; if  $t_{\text{rCD}}$  is greater than the specified  $t_{\text{rCD}}(\text{max})$  limit, then access time is controlled exclusively by  $t_{\text{CAC}}$ .
9. Operation with the  $t_{\text{rAD}}(\text{max})$  limit insures that  $t_{\text{rAC}}(\text{max})$  can be met,  $t_{\text{rAD}}(\text{max})$  is specified as a reference point only; if  $t_{\text{rAD}}$  is greater than the specified  $t_{\text{rAD}}(\text{max})$  limit, then access time is controlled exclusively by  $t_{\text{AA}}$ .
10.  $t_{\text{WCS}}$ ,  $t_{\text{rWD}}$ ,  $t_{\text{CWD}}$ ,  $t_{\text{AWD}}$  and  $t_{\text{CPW}}$  are not restrictive operating parameters. They are included in the data sheet as electrical characteristics only if  $t_{\text{WCS}} \geq t_{\text{WCS}}(\text{min})$  the cycle is an early write cycle and the data out pin will remain open circuit (high impedance) throughout the entire cycle; if  $t_{\text{rWD}} \geq t_{\text{rWD}}(\text{min})$ ,  $t_{\text{CWD}} \geq t_{\text{CWD}}(\text{min})$ ,  $t_{\text{AWD}} \geq t_{\text{AWD}}(\text{min})$  and  $t_{\text{CPW}} \geq t_{\text{CPW}}(\text{min})$ , the cycle is a read modify write and the data output will contain data read from the selected cell; if neither of the above sets of conditions is satisfied, the condition of the data out (at access time) is indeterminate.
11. These parameters are referenced to  $\overline{\text{CAS}}$  leading edge in early write cycles and to  $\overline{\text{WE}}$  leading edge in delayed write or a read modify write cycle.
12. An initial pause of 100 $\mu\text{s}$  is required after power up followed by a minimum of eight initialization cycles ( $\overline{\text{RAS}}$  only refresh cycle or  $\overline{\text{CAS}}$  before  $\overline{\text{RAS}}$  refresh cycle). If the internal refresh counter is used, a minimum of eight  $\overline{\text{CAS}}$  before  $\overline{\text{RAS}}$  refresh cycles is required.
13.  $t_{\text{RASC}}$  defines  $\overline{\text{RAS}}$  pulse width in fast page mode cycles.
14. Access time is determined by the longer of  $t_{\text{AA}}$  or  $t_{\text{CAC}}$  or  $t_{\text{ACP}}$ .



15. Test mode operation specified in this data sheet is 8 bit test function controlled by control address bits RA10, CA10 and CA0. This test mode operation can be performed by  $\overline{WE}$  and  $\overline{CAS}$  before  $\overline{RAS}$  (WCBR) refresh cycle. Refresh during test mode operation will be performed by normal read cycles or by WCBR refresh cycles. When the state of eight test bits accord each other, the condition of the output data is high level. When the state of test bits do not accord, the condition of the output data is low level. Data output pin is DOUT and data input pin is DIN. In order to end this test mode operation, perform a  $\overline{RAS}$  only refresh cycle or a  $\overline{CAS}$  before  $\overline{RAS}$  refresh cycle.
16. In a test mode read cycle, the value of  $t_{RAC}$ ,  $t_{AA}$ ,  $t_{CAC}$  and  $t_{ACP}$  is delayed for 2ns to 5ns for the specified value. These parameters should be specified in test mode cycles by adding the above value to the specified value in this data sheet.

## Timing Waveforms

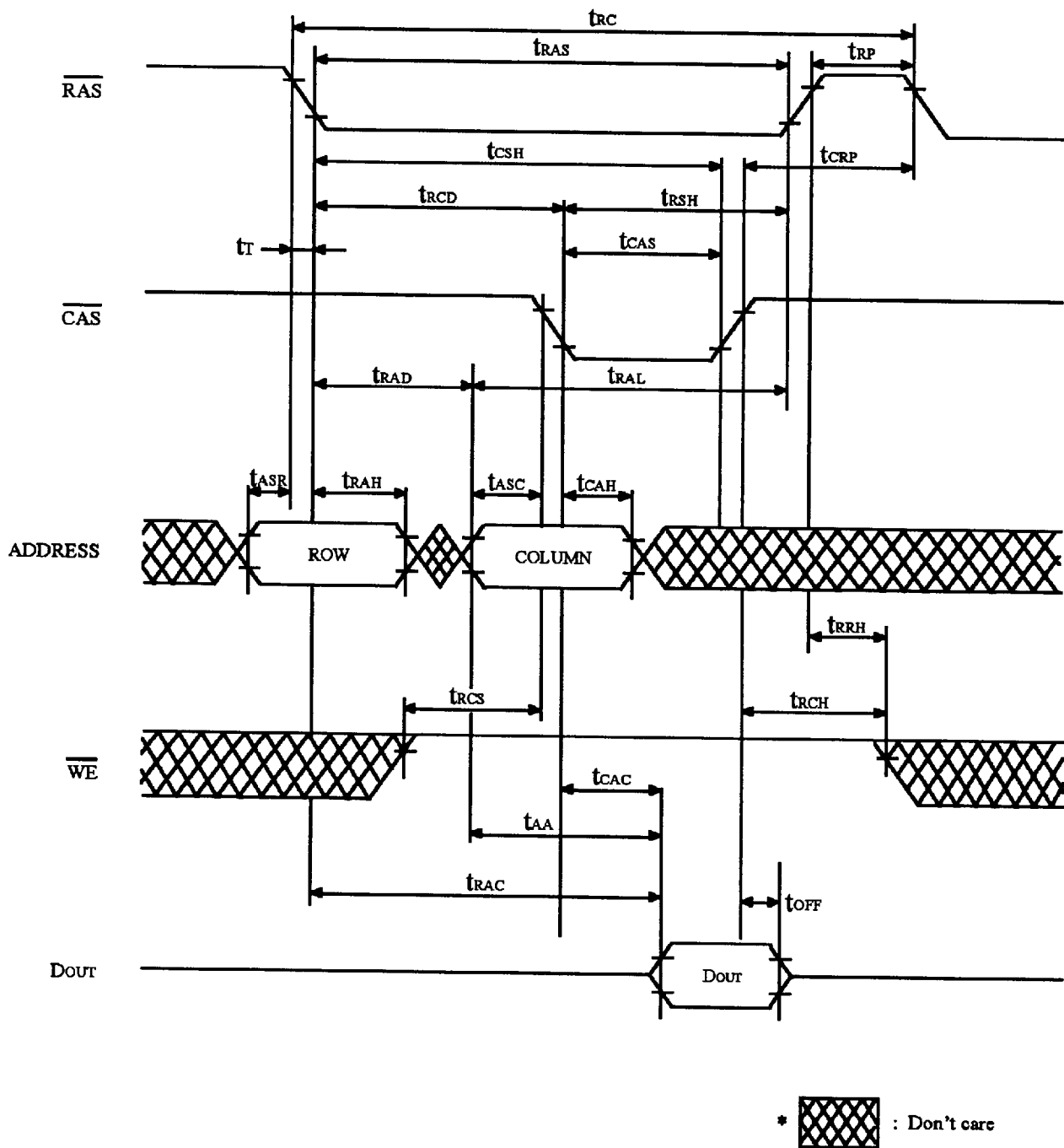
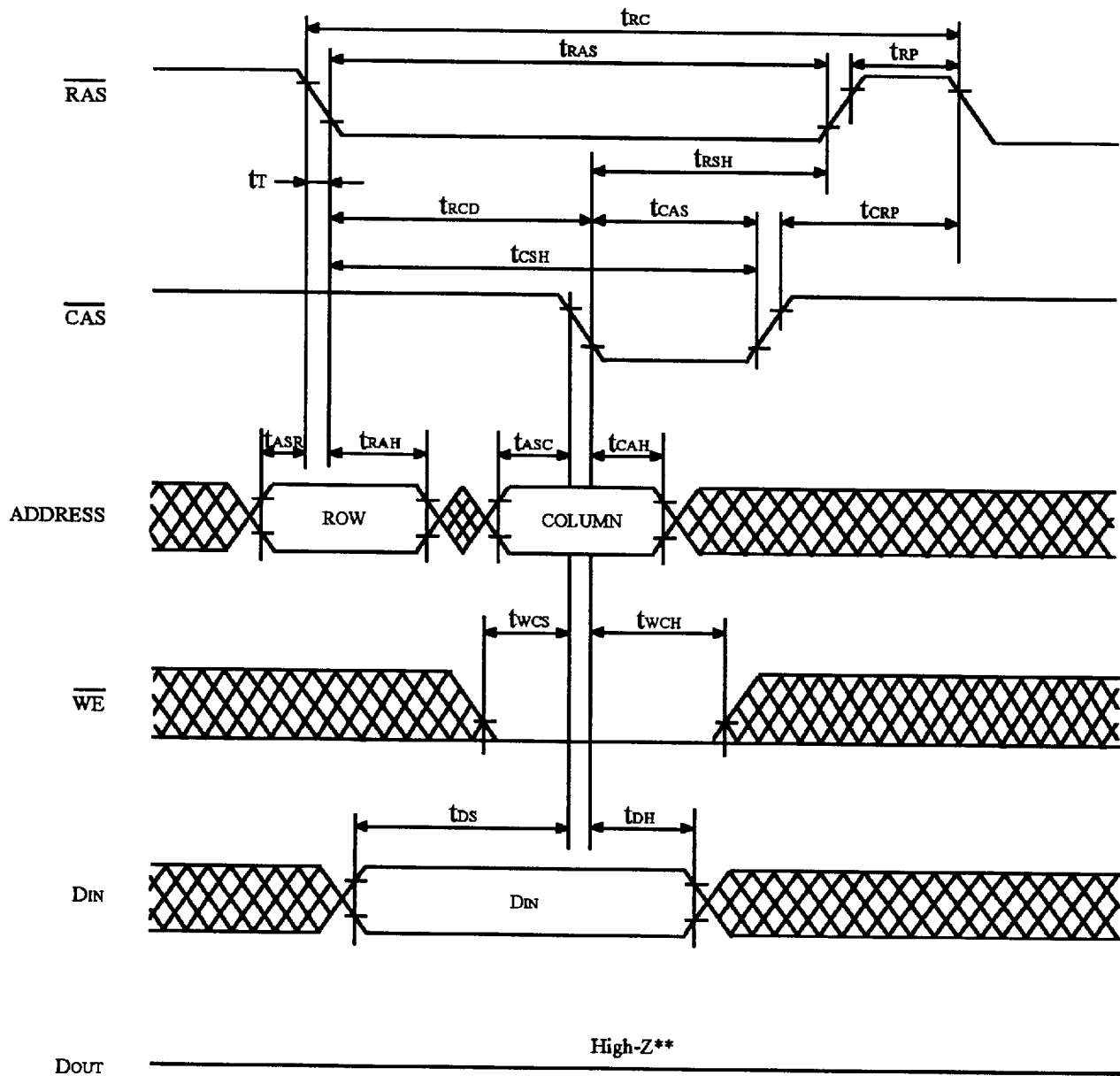


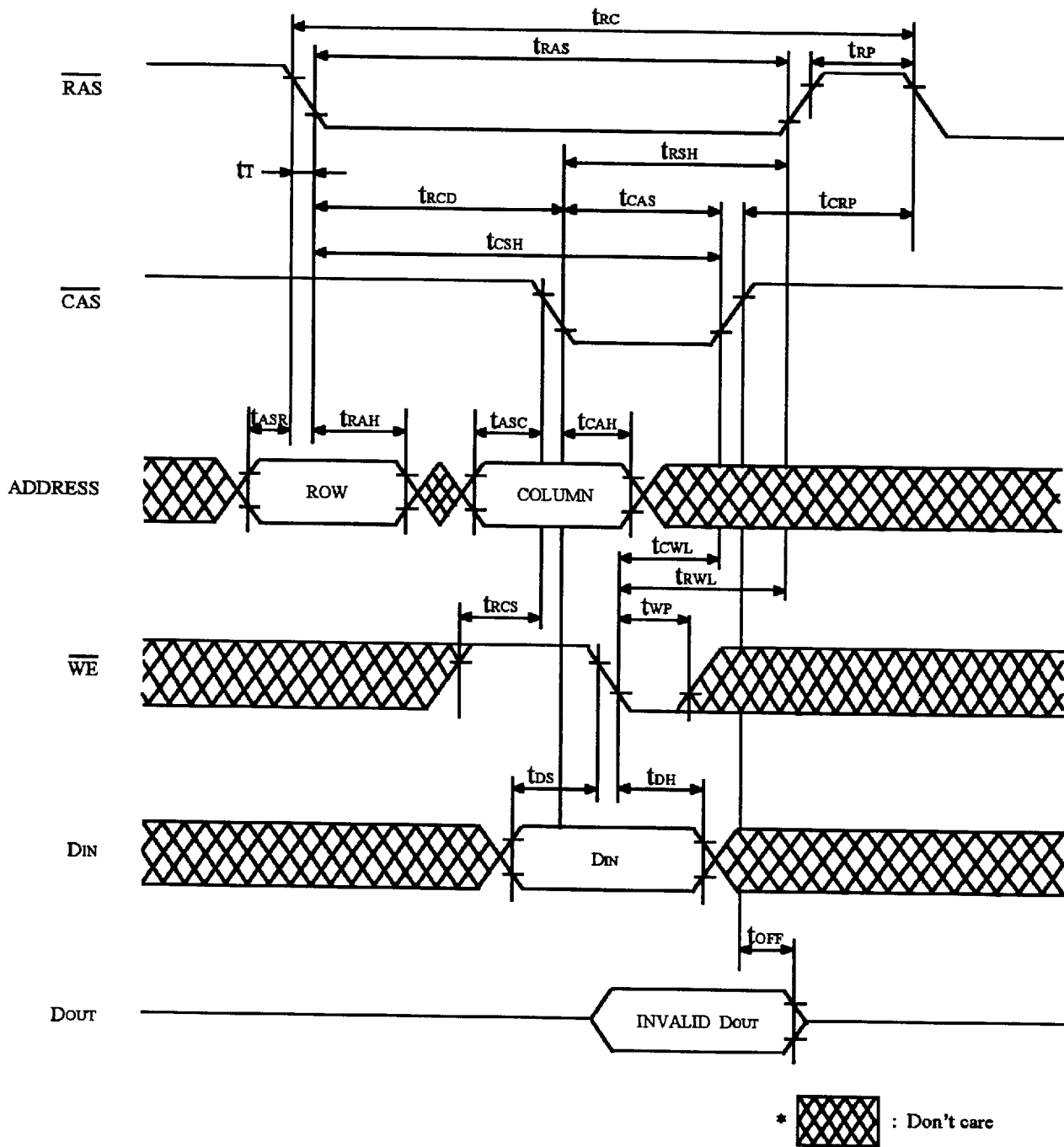
FIGURE 1. READ CYCLE



\*  : Don't care

\*\*  $t_{WCS} \geq t_{WCS}(\text{min})$

FIGURE 2. EARLY WRITE CYCLE



**FIGURE 3. DELAYED WRITE CYCLE**

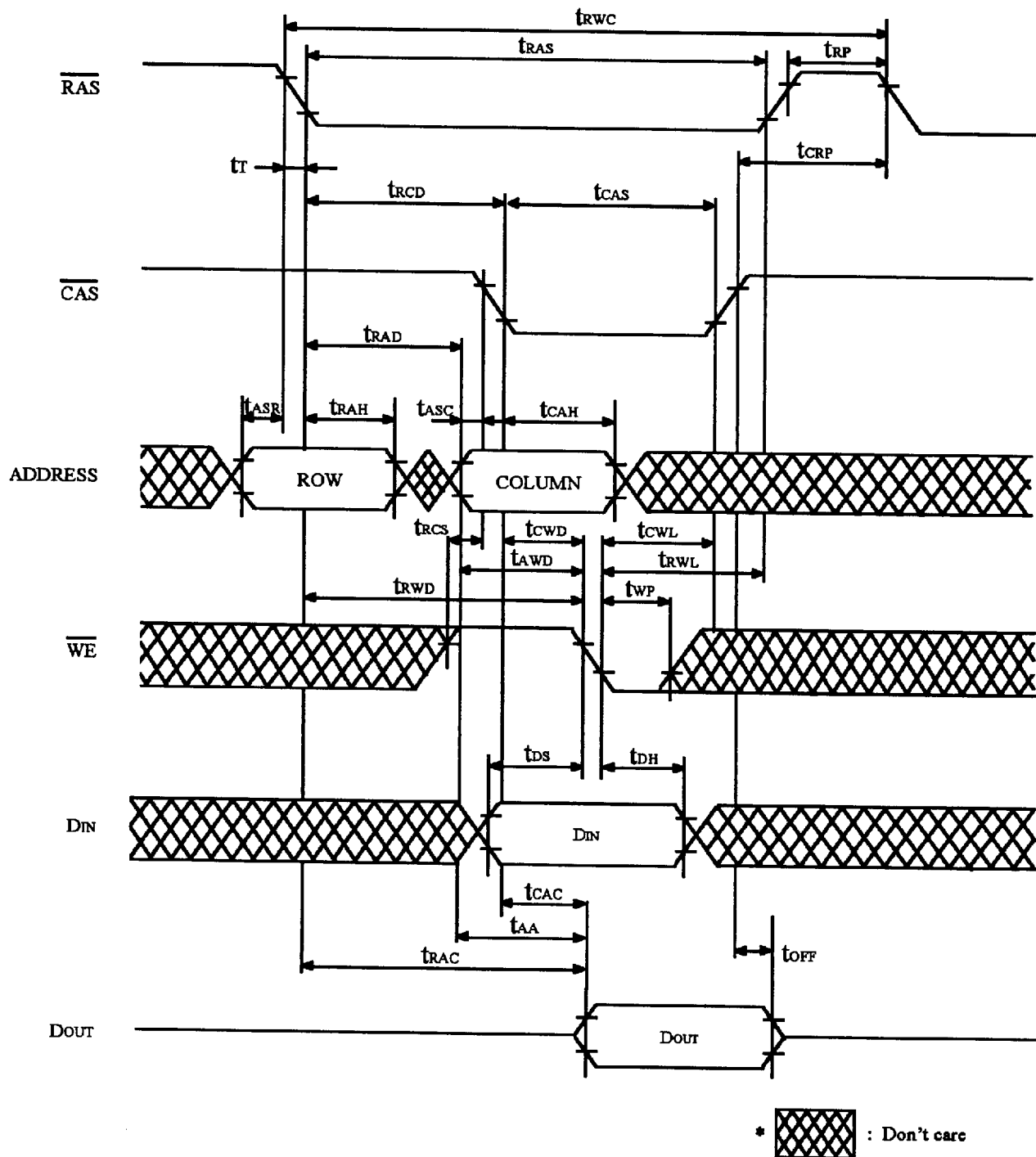
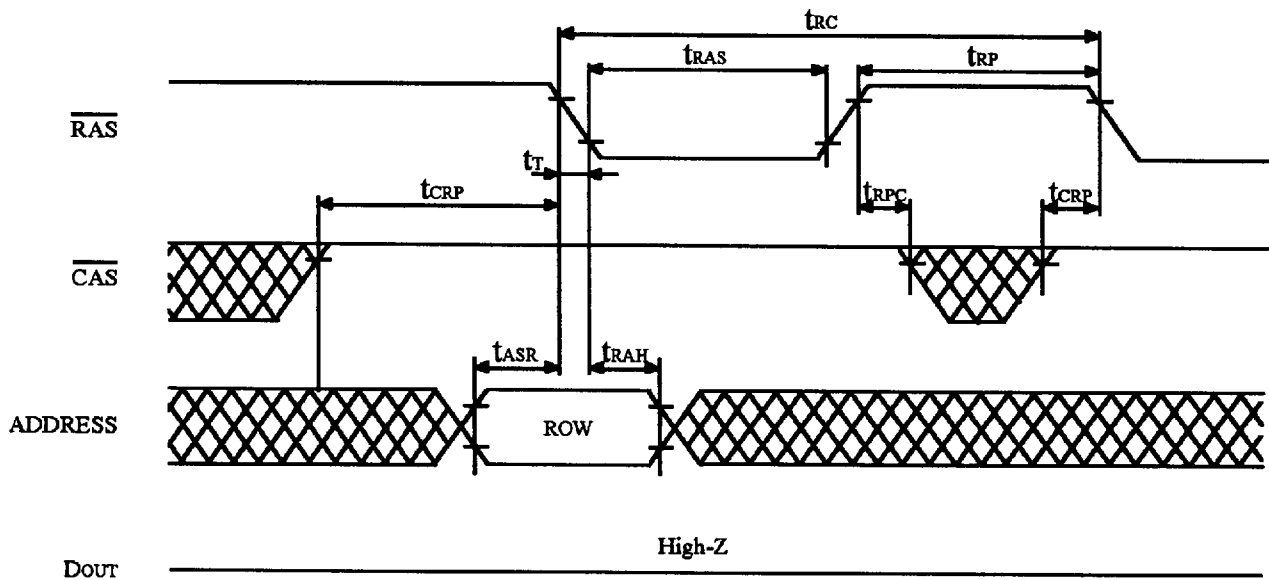


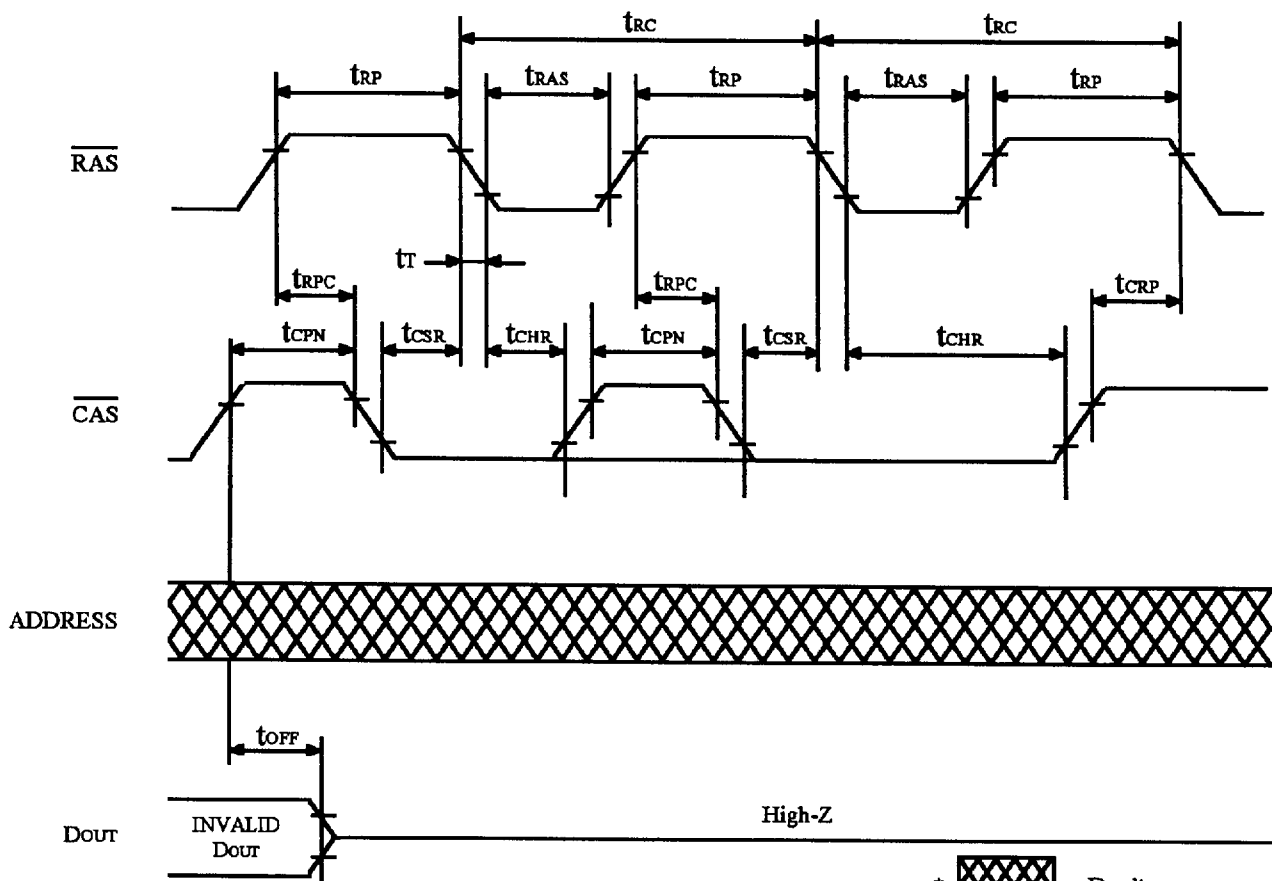
FIGURE 4. READ MODIFY WRITE CYCLE



\*  $\overline{WE}$  : Don't care

FIGURE 5.  $\overline{RAS}$  ONLY REFRESH CYCLE

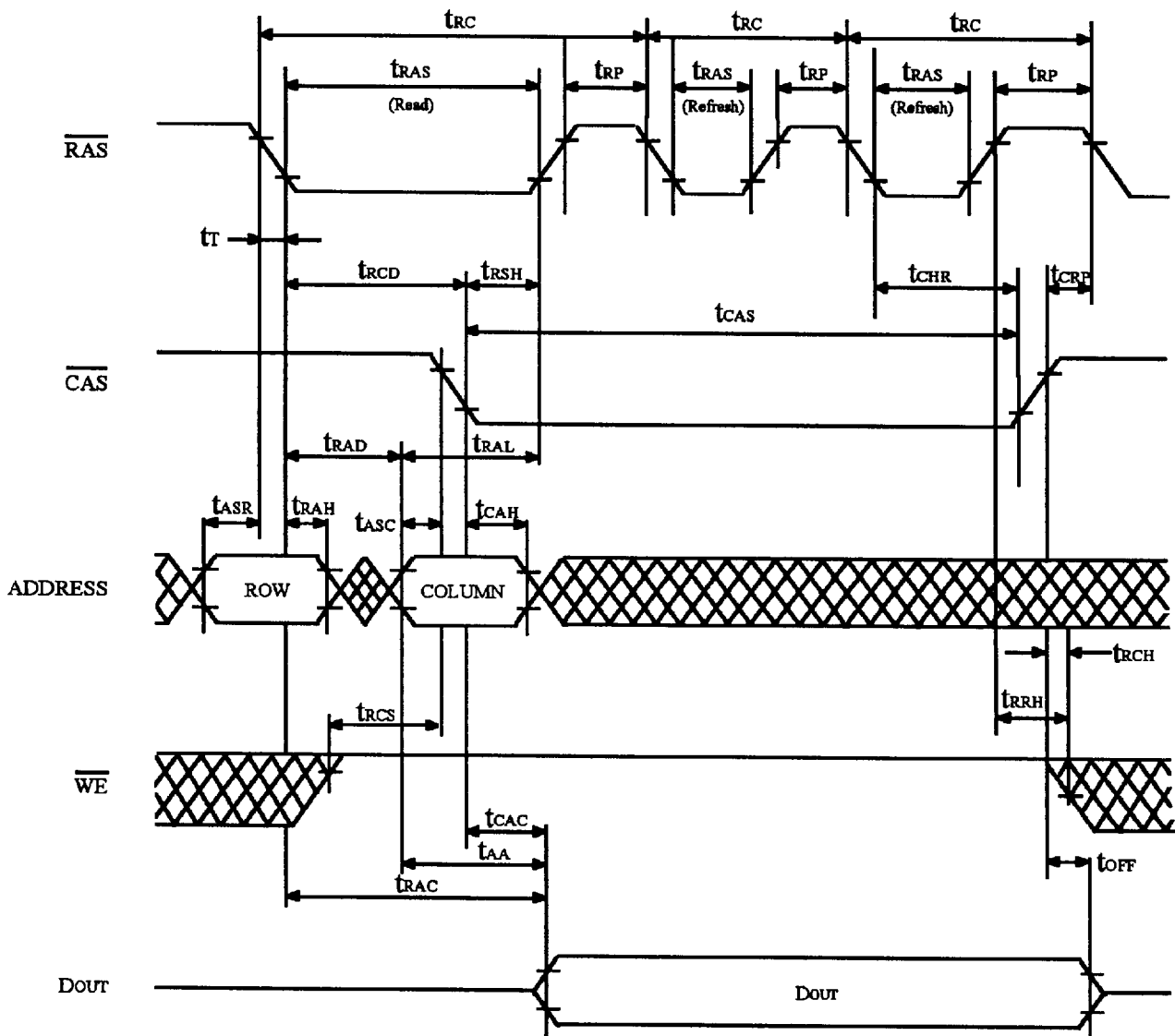
\*\* Refresh address : A0~A9



\*  : Don't care

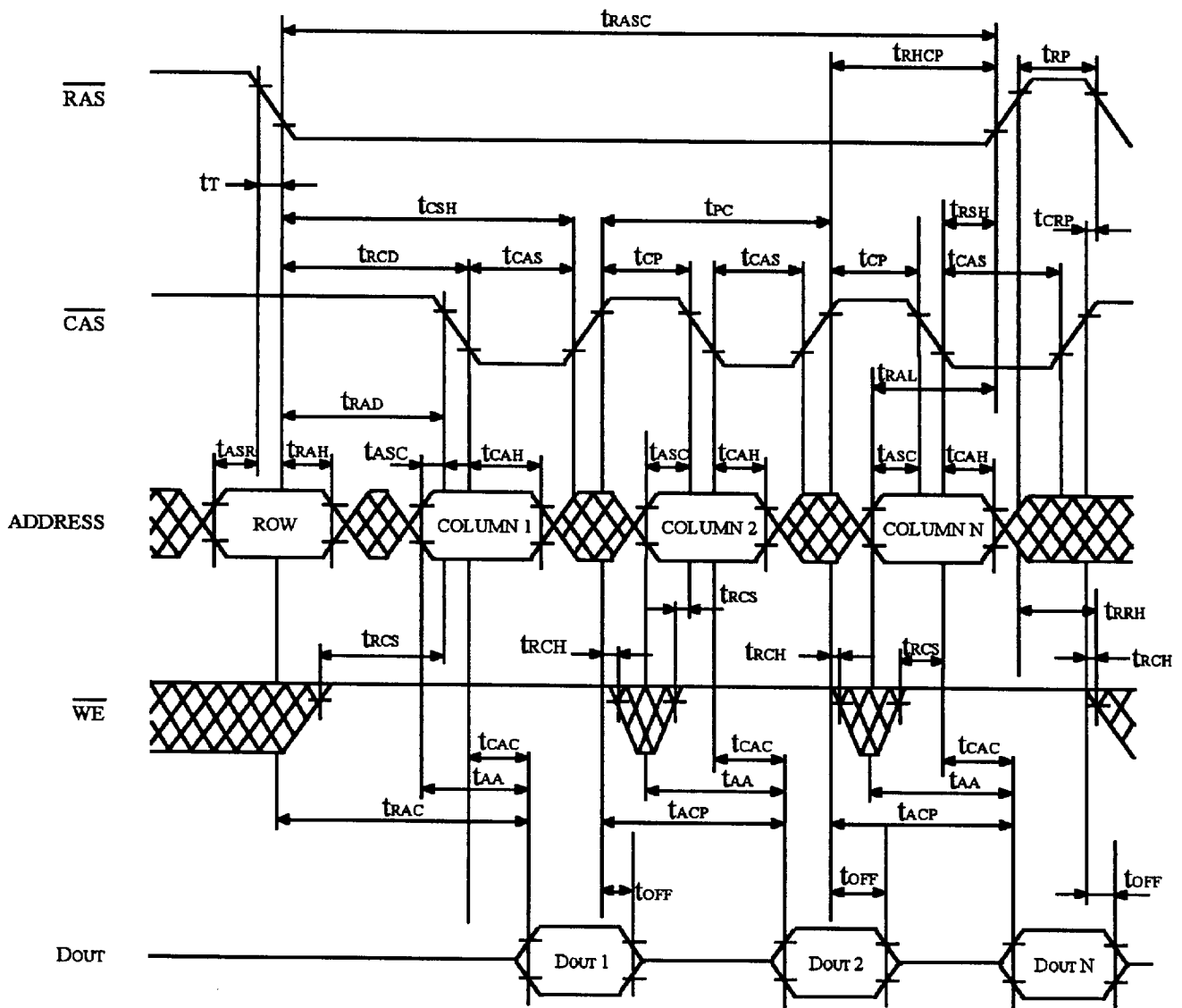
\*\*  $\overline{WE}$  :  $V_{IH}$

FIGURE 6.  $\overline{CAS}$  BEFORE  $\overline{RAS}$  REFRESH CYCLE



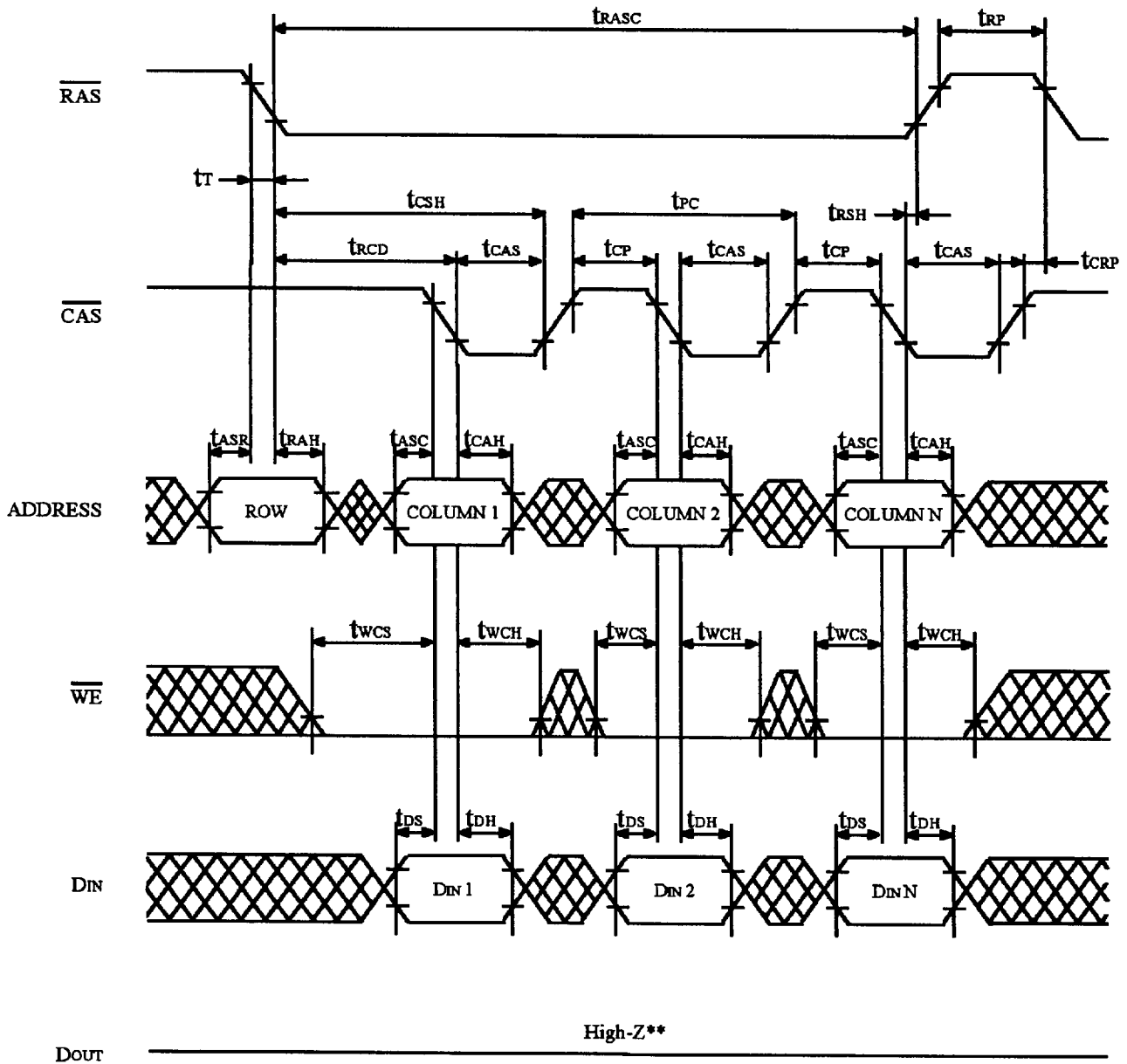
\*  : Don't care

FIGURE 7. HIDDEN REFRESH CYCLE



\*  : Don't care

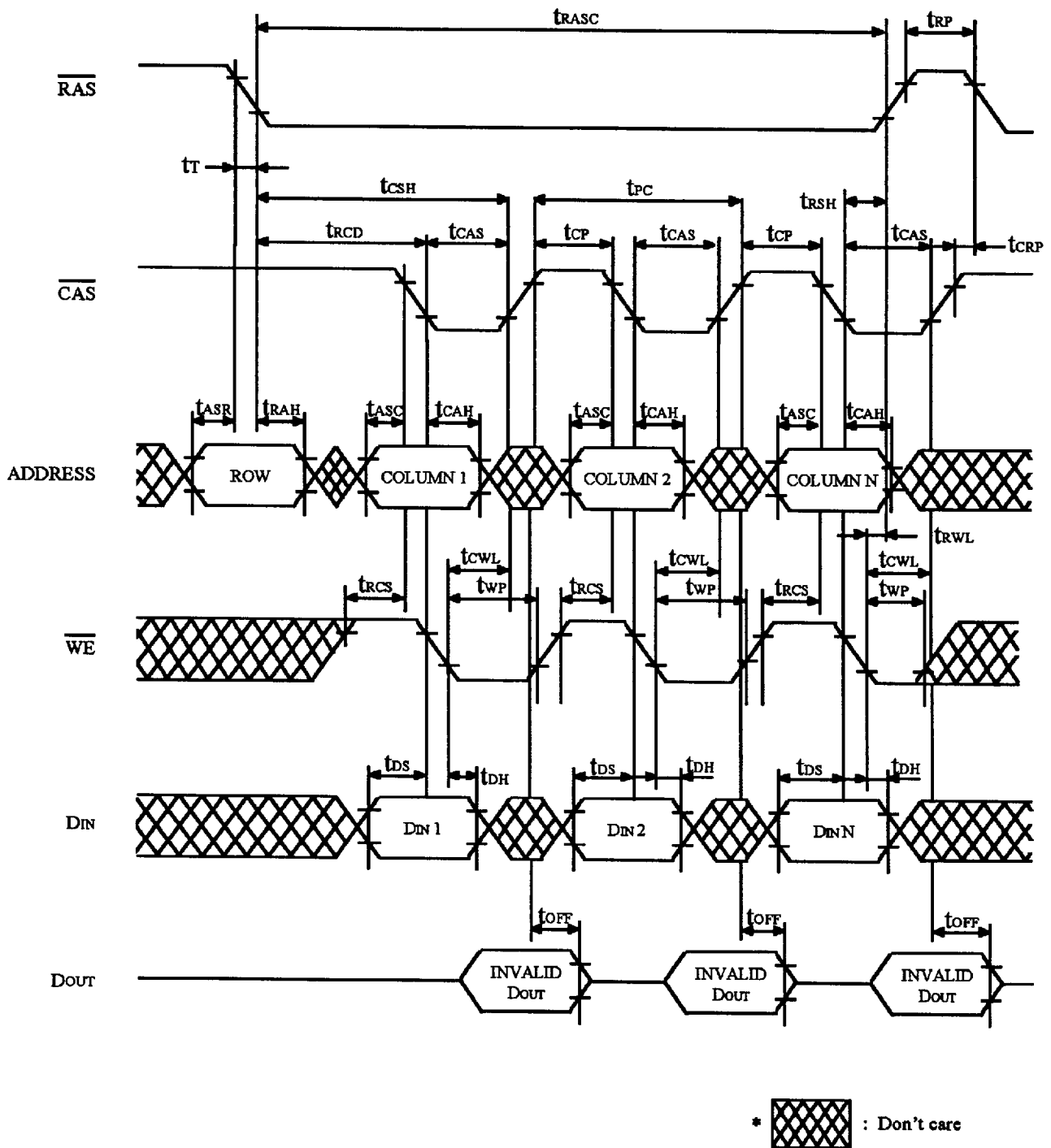
FIGURE 8. FAST PAGE MODE READ CYCLE



\*  : Don't care

\*\*  $t_{WCS} \geq t_{WCS}(\text{min})$

**FIGURE 9. FAST PAGE MODE EARLY WRITE CYCLE**



**FIGURE 10. FAST PAGE MODE DELAYED WRITE CYCLE**

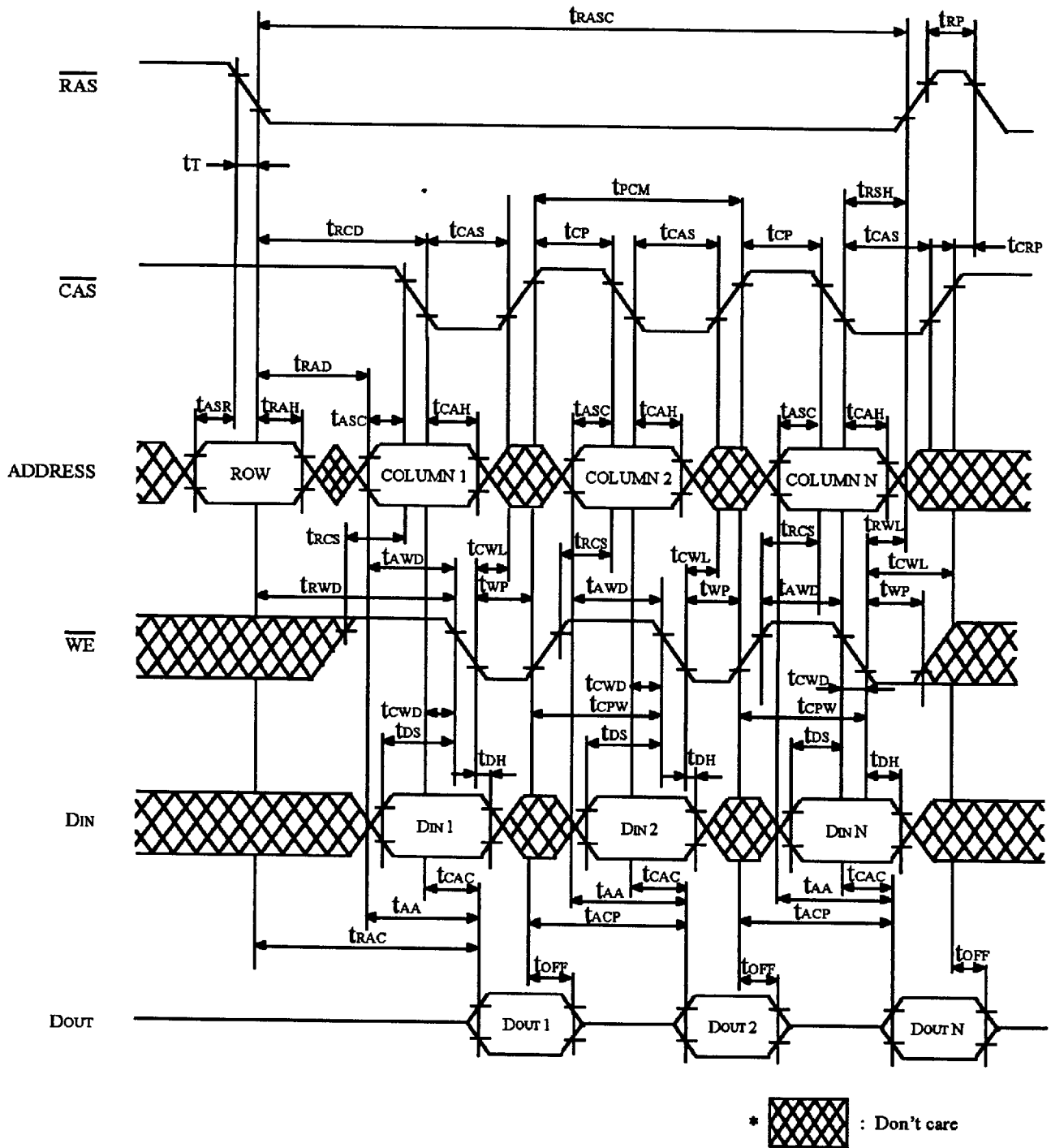


FIGURE 11. FAST PAGE MODE READ MODIFY WRITE CYCLE

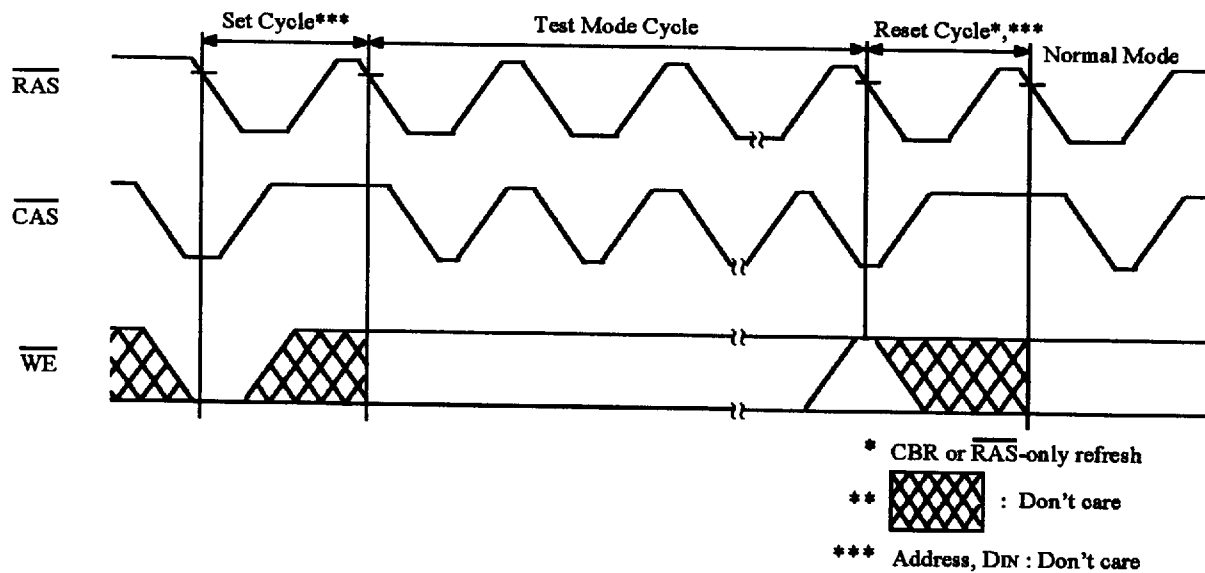


FIGURE 12. TEST MODE CYCLE

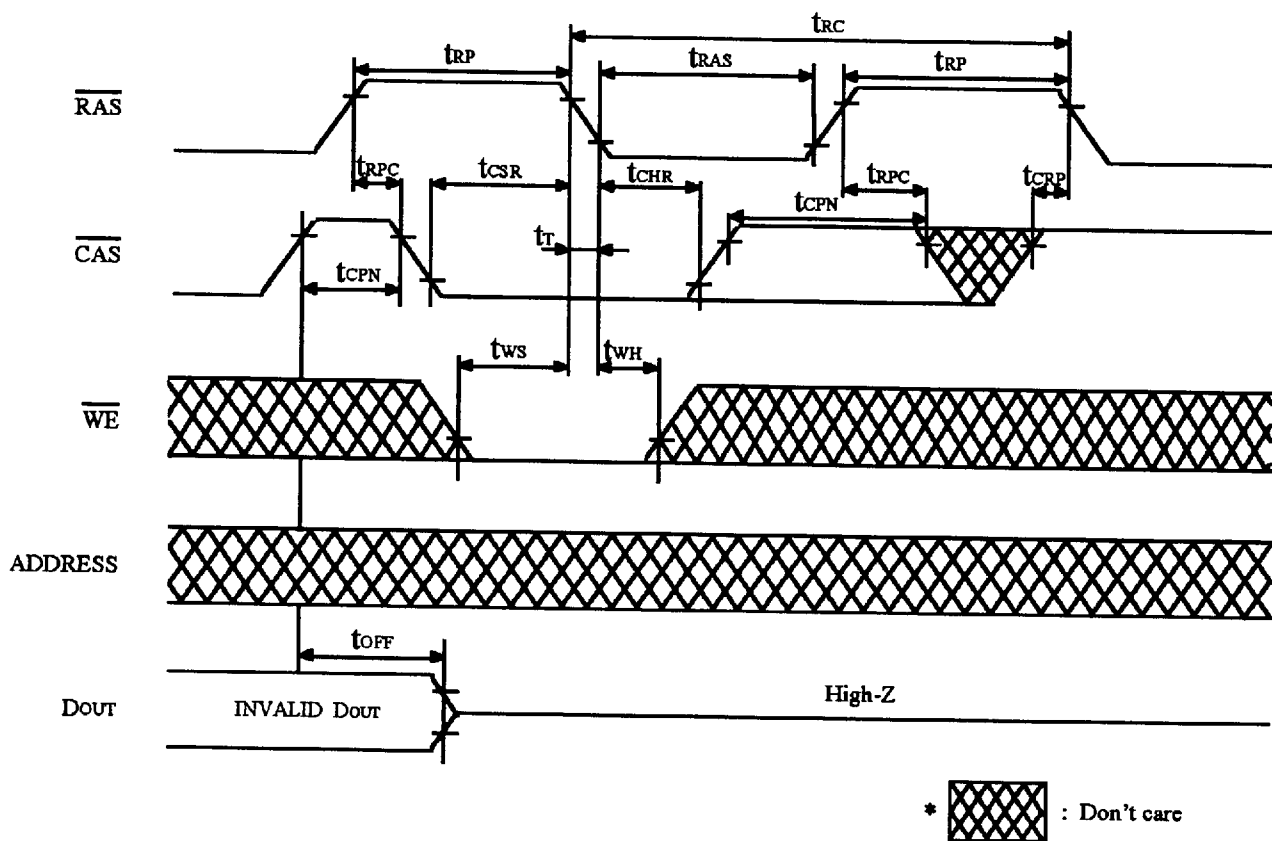
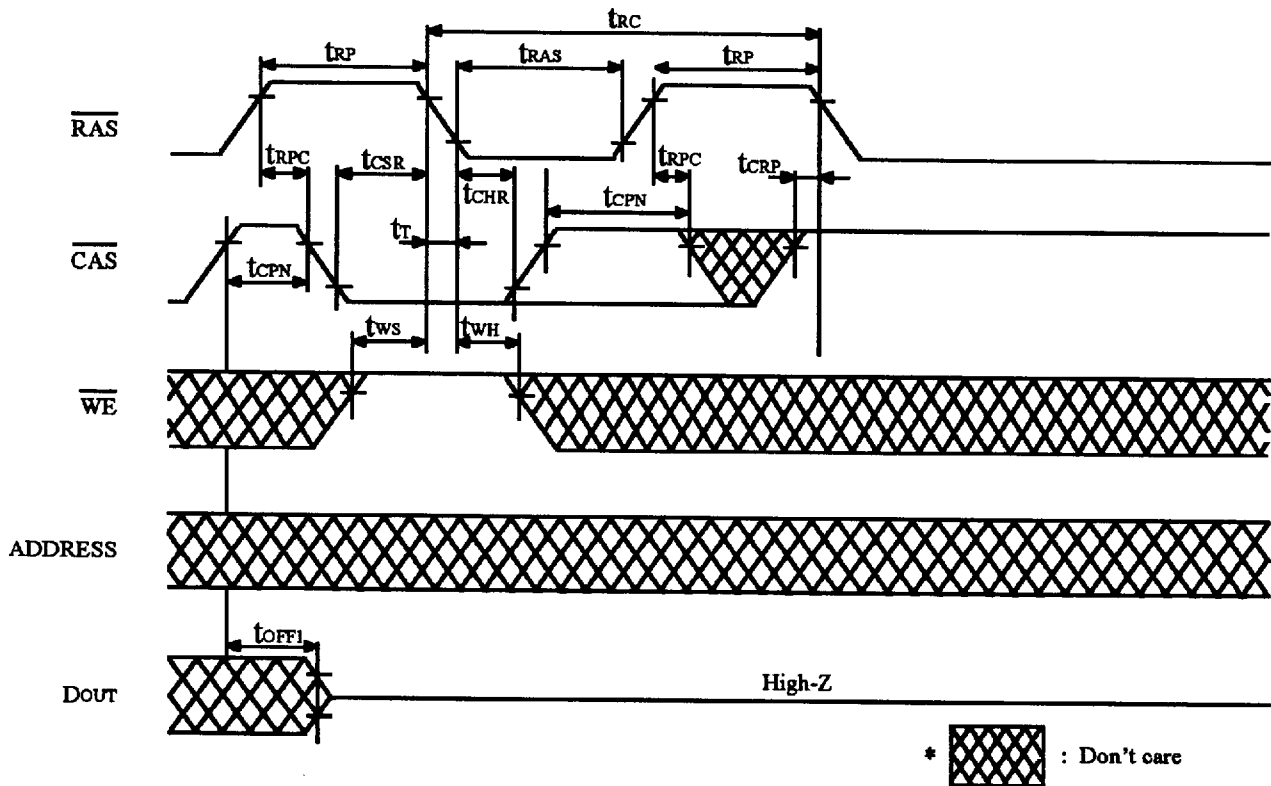
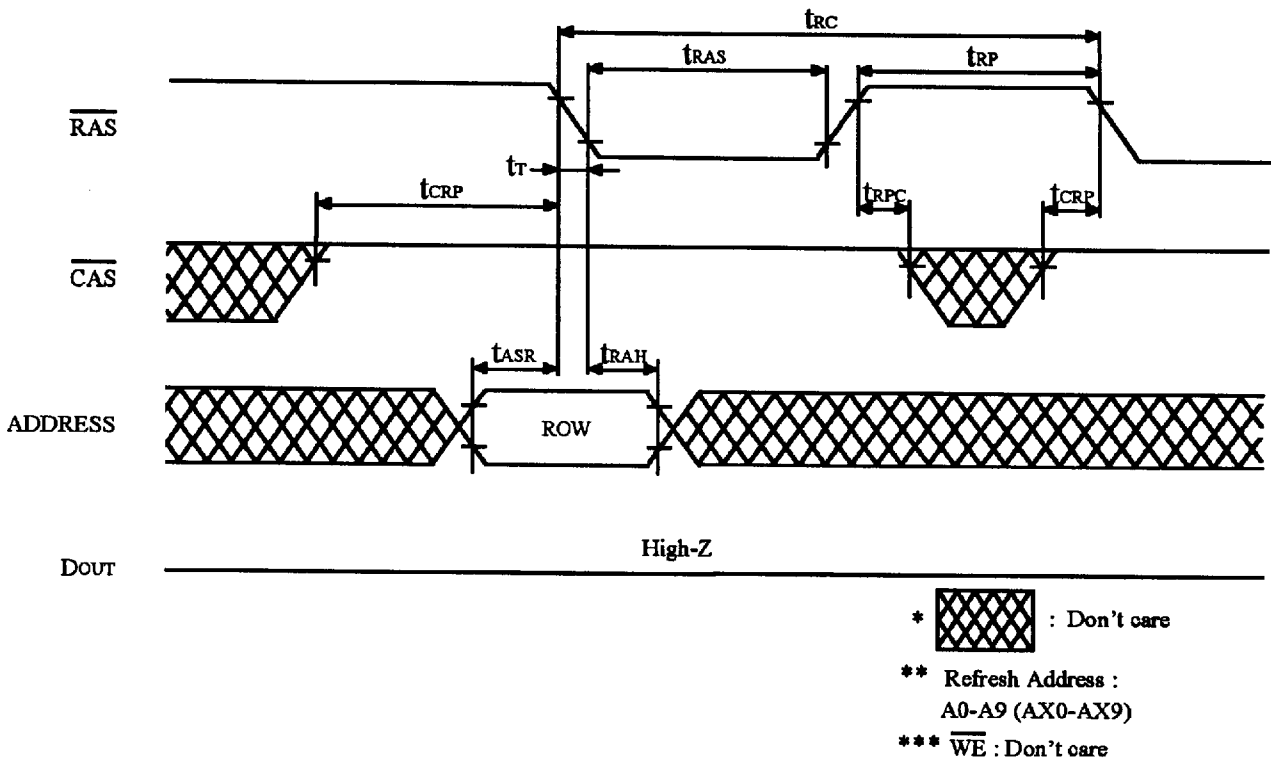


FIGURE 13. TEST MODE SET CYCLE

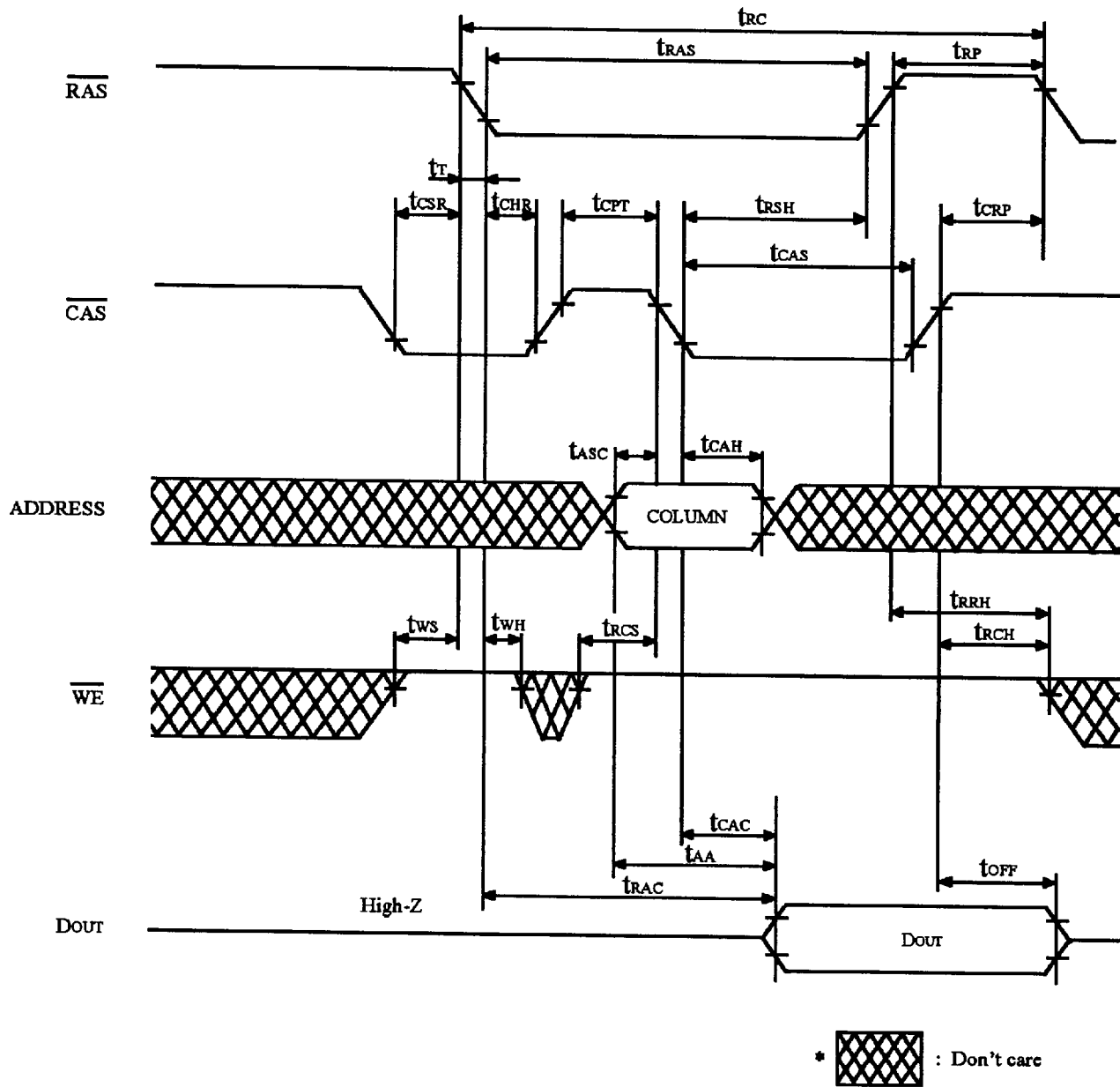
**Test Mode Reset Cycle**



**FIGURE 14.  $\overline{\text{CAS}}$  BEFORE  $\overline{\text{RAS}}$  REFRESH CYCLE**



**FIGURE 15.  $\overline{\text{RAS}}$  ONLY REFRESH CYCLE**



**FIGURE 16.  $\overline{\text{CAS}}$  BEFORE  $\overline{\text{RAS}}$  REFRESH COUNTER CHECK CYCLE (READ)**

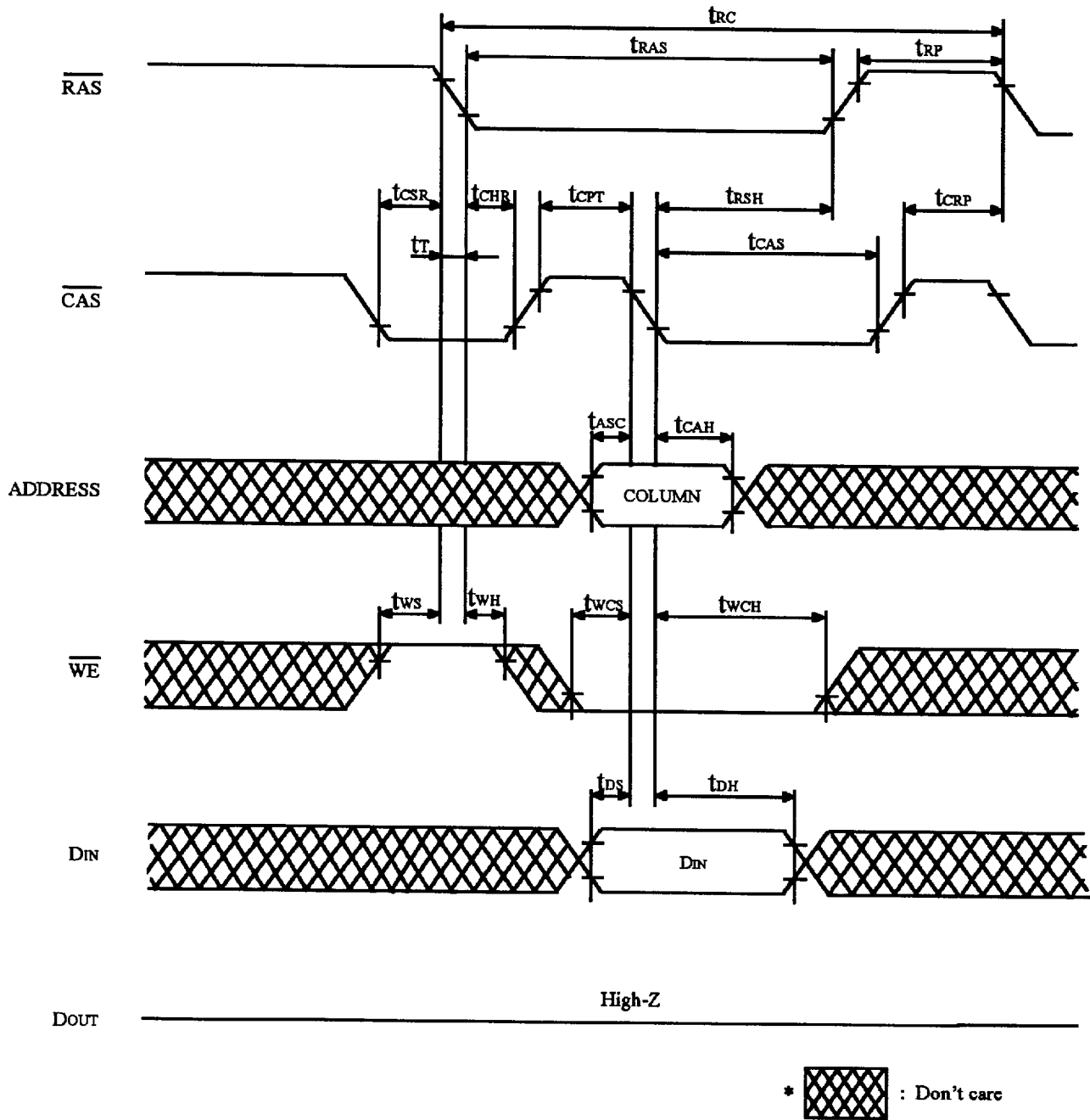
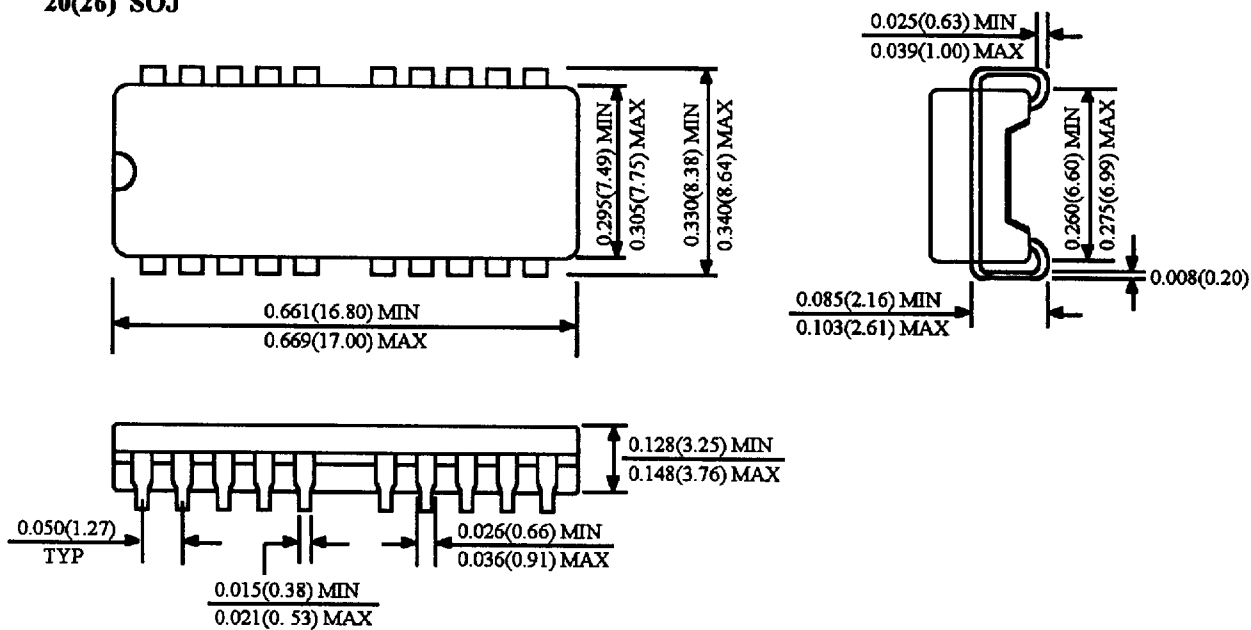


FIGURE 17.  $\overline{\text{CAS}}$  BEFORE  $\overline{\text{RAS}}$  REFRESH COUNTER CHECK CYCLE (WRITE)

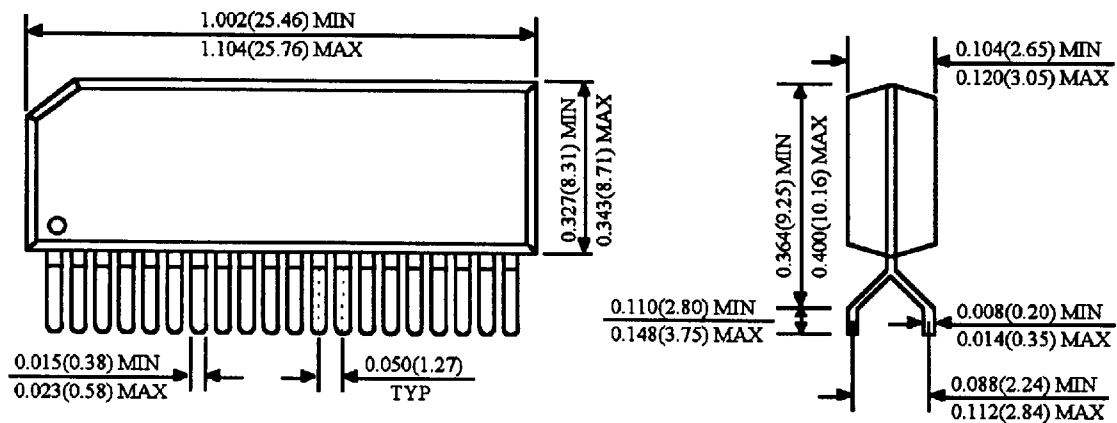
**Package Dimension**

Unit: Inches (mm)

**20(26) SOJ**



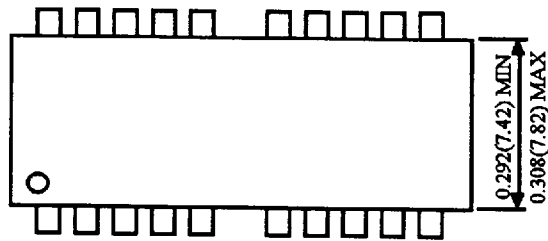
**20 ZIP**



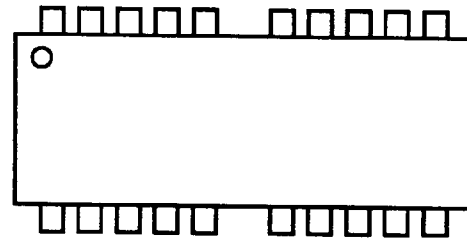
Package Dimension

Unit: Inches (mm)

20 (26) TSOP (TYPE. II)



GM71C4100CT/CLT



GM71C4100CR/CLR

